



501.42869X00

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

H. CHAKIHARA, et al.

Application No.:

10/629,733

Filed:

July 30, 2003

For:

A SEMICONDUCTOR EMORY DEVICE AND A METHOD OF

MANUFACTURING THE SAME, A METHOD OF

MANUFACTURING A VERTICAL MISFET AND A VERTICAL

MISFET, AND A METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE AND A SEMICONDUCTOR

DEVICE

Art Unit:

2826

Examiner:

F. Abraham

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR §§ 1.97 & 1.98

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 April 26, 2004

Sir:

In the matter of the above-identified application, Applicants are submitting herewith a copy of a U.S. application Serial No. 10/465,550 and copies of the documents listed in the attached form PTO/SB/08A, cited in the related application for the Examiner's consideration.

This Information Disclosure Statement is being submitted, on information and belief, before the mailing date of a first Office Action on the merits.

To the extent the documents listed on the attached form PTO/SB/08A are not in the English language, the requirement of 37 CFR § 1.98(a)(3). For a concise explanation of the relevance is satisfied by an English language version abstract or